## Spin-Halle ect on edge magnetization and electric conductance of a 2D sem iconductor strip

A.G.Mal'shukov<sup>1</sup>, L.Y.W ang<sup>2</sup>, C.S.Chu<sup>2</sup> and K.A.Chao<sup>3</sup>

<sup>1</sup>Institute of Spectroscopy, Russian Academ y of Science, 142190, Troitsk, Moscow oblast, Russia

<sup>2</sup>D epartm ent of E lectrophysics, N ational C hiao T ung U niversity, H sinchu 30010, T aiw an

<sup>3</sup> Solid State Theory D ivision, D epartm ent of Physics, Lund University, S-22362 Lund, Sweden

The intrinsic spin-Halle ect on spin accumulation and electric conductance in a di usive regime of a 2D electron gas has been studied for a 2D strip of a nite width. It is shown that the spin polarization near the anks of the strip, as well as the electric current in the longitudinal direction exhibit damped oscillations as a function of the width and strength of the D resselhaus spin-orbit interaction. Cubic terms of this interaction are crucial for spin accumulation near the edges. As expected, no e ect on the spin accumulation and electric conductance have been found in case of R ashba spin-orbit interaction.

PACS num bers: 72.25 D c, 71.70 E j, 73.40 Lq

Spintronics is a fast developing area to use electron spin degrees of freedom in electronic devices [1]. One of its most challenging goals is to nd a method form anipulating electron spins by electric elds. The spin-orbit interaction (SO I), which couples the electron m om entum and spin, can be a m ediator between the charge and spin degrees of freedom . Such a coupling gives rise to the so called spin-Halle ect (SHE) which attracted much interest recently. Due to SO I the spin ow can be induced perpendicular to the DC electric eld, as has been predicted for systems containing spin-orbit impurity scatterers [2]. Later, sim ilar phenom enon was predicted for noncentrosymm etric sem iconductors with spin split electron and hole energy bands  $[\beta]$ . It was called the intrinsic spin-Halle ect, in contrast to the extrinsic in purity induced e ect, because in the form er case it originates from the electronic band structure of a sem iconductor sam ple. Since the spin current carries the spin polarization, one would expect a buildup of the spin density near the sam ple boundaries. In fact, this accumulated polarization is a rst signature of SHE which has been detected experimentally, con ming thus the extrinsic SHE [4] in sem iconductor Im s and intrinsic SHE in a 2D hole gas [5]. On the other hand, there were still no experim ental evidence of intrinsic SHE in 2D electron gases. The possibility of such an e ect in macroscopic samples with a nite elastic m ean free path of electrons caused recently m uch debates. It has been shown analytically [6,7,8,9,10,11] and num erically [12] that in such system s SHE vanishes at arbitrary weak disorder in DC lim it, for isotropic, as well as an isotropic [10] in purity scattering, when SO I is represented by the so called R ashba interaction [13]. A s one can expect in this case, there is no spin accum ulation at the sam ple boundaries, except for the pockets near the electric contacts [7]. At the same time, the D resselhaus SOI [14], which dom inates in symmetric quantum wells, gives a nite spin-Hall conductivity [11]. The latter can be of the order of its universal value e=8 ~. The same has been shown for the cubic Rashba interaction in hole system s [12, 15]. In this connection an important question is what sort of the spin accumulation could D resselhaus SO I induce near sample boundaries. Another problem which, as far as we know, was not discussed in literature, is how the electric current along the applied electric eld will change under SHE. In the present work we will use the di usion approximation for the electron transport to derive the drift di usion equations with corresponding boundary conditions for the spin and charge densities coupled to each other via SO I of general form. Then the spin density near the anks of an in nite 2D strip and the correction to its longitudinal electric resistance will be calculated for D resselhaus and R ashba SO I.

Let us consider 2D EG con ned in an in nite 2D strip. The boundaries of the strip are at y = d=2. The electric eld E drives the DC current in the x-direction and induces the spin-Hall current in the y-direction. This current leads to spin polarization buildup near boundaries. Since d  $k_F^{-1}$ , where  $k_F$  is the Ferm i wavector, this problem can be treated within the sem iclassical approximation. Moreover, we will assume that d is much larger than the electron elastic mean free path 1, so that the drift-di usion equation can be applied for description of the spin and charge transport. Our goal is to derive this equation for SO I of general form

$$H_{so} = h_k \qquad ; \qquad (1)$$

where (x; y; z) is the Paulim atrix vector, and the elective magnetic eld  $h_k = h_k$  is a function of the two-dimensional wave-vector k.

W e start from determ ining linear responses to them agnetic B (r;t) and electric V (r;t) potentials. The magnetic potentials are introduced in order to derive the diffusion equation and play an auxiliary role. The corresponding one-particle interaction with the spin density is de ned as  $H_{sp} = B$  (r;t) . These potentials induce the spin and charge densities, S (r;t) and n (r;t), respectively. D ue to SO I the charge and spin degrees of freedom are coupled, so that the electric potential can induce the

spin density [16] and vice versa. Therefore, it is convenient to introduce the four-vector of densities  $D_i(r;t)$ , such that  $D_0(r) = n(r;t)$  and  $D_{x;y;z}(r;t) = S_{x;y;z}(r;t)$ . The corresponding four-vector of potentials will be denoted as  $_i(r;t)$ . A coordingly, the linear response equations can be written in the form

$$D_{i}(r;t) = d^{2}r^{0}dt^{0} \qquad ij (r;r^{0};t \quad t) \quad j (r^{0};t^{0})$$

$$+ D_{i}^{0}(r;t): \qquad (2)$$

The response functions  $_{ij}(r;r^{0};t)$  can be expressed in a standard way [17] through the retarded and advanced G reen functions  $G^{r}(r;r^{0};t)$  and  $G^{a}(r;r^{0};t)$ . In the Fourier representation we get

$$i_{j}(\mathbf{r};\mathbf{r}^{0};!) = i! \frac{d!}{2} \frac{d!}{2} \frac{(n_{\rm F}(!))}{(n_{\rm F}(!))} h Tr[G^{a}(\mathbf{r}^{0};\mathbf{r};!)]$$

$$i_{\rm G}^{r}(\mathbf{r};\mathbf{r}^{0};!) + !) j]i; \qquad (3)$$

where  $_0 = 1$ ,  $_i = _i$  at i = x;y;z and  $n_F$  (!) is the Ferm i distribution function. The time Fourier components of densities  $D_i^0(r;t)$  at !  $E_F$  are de ned as

$$D_{i}^{0}(\mathbf{r};!) = i \frac{d^{2}r^{0}}{d^{2}r^{0}} j(\mathbf{r}^{0};!) \frac{d!^{0}}{2}n_{F}(!^{0})$$

$$hTr[G^{r}(\mathbf{r};\mathbf{r}^{0};!^{0}) G^{r}(\mathbf{r}^{0};\mathbf{r};!^{0}) j$$

$$G^{a}(\mathbf{r};\mathbf{r}^{0};!^{0}) G^{a}(\mathbf{r}^{0};\mathbf{k};!^{0}) j]i: (4)$$

The trace in Eqs. (3-4) runs through the spin variables, and the angular brackets denote the average over the random distribution of impurities. W ithin the sem iclassical approxim ation the average of the product of G reen functions can be calculated perturbatively. Ignoring the weak localization e ects, the perturbation expansion consists of the so called ladder series [17, 18]. At sm all! and large r<sup>0</sup> j they describe the particle and spin di usion proŗ cesses. The building blocks for the perturbation expansion are the average G reen functions  $G^r$  and  $G^a$ , together with the pair correlator of the in purity scattering potentialU<sub>sc</sub>(r). A simple model of the short-range isotropic potential gives  $hU_{sc}(r)U_{sc}(r^0)i =$  $(r \quad r^{0}) = N_{0}$ , where N $_{\rm 0}$  is the electron density of states at the Ferm i energy and = 1=2 . W ithin the sem iclassical approach the explicit behavior of the electron wave functions near the boundaries of the strip is not im portant. Therefore, the bulk expressions can be used for the average G reen functions. Hence, in the plane wave representation

$$G^{r}(k;!) = [G^{a}(k;!)]^{Y} = (! \quad E_{k} \quad h_{k} \quad + i^{1};$$
(5)

where  $E_k = k^2 = (2m)$   $E_F$ . Since the integral in (4) rapidly converges at r  $r^0j$ .  $k_F^{-1}$ ,  $D_i^0(r;!)$  are given by the local values of potentials. From (4)-(5) one easily obtains the local equilibrium densities

$$D_{i}^{0}(r;!) = 2N_{0}(r;!)$$
 (6)

In their turn, the nonequilibrium spin and charge densities are represented by the rst term in Eq. (2). Within the di usion approximation this term is given by the gradient expansion of (3) [18]. Such an expansion is valid as far as spatial variations of D<sub>i</sub> (r;!) are relatively small within the length of the order of the mean free path 1. The length scale for spin density variations near the boundaries of the strip is given by  $v_F = h_{k_F}$ . Hence, the diffusion approximation can be employed only in the dirty lim it  $h_{k_F}$  1= . The di usion equation is obtained after the ladder summation in the rst term of Eq. (3) and multiplying this equation by the operator inverse to  $_{ij}$  (r;r<sup>0</sup>;!), as it has been previously done in [19, 20].

A fler som e algebraic m anipulations one gets

$$D^{ij}(D_j D^0_j) = i! D_i;$$
(7)

where the di usion operator D<sup>ij</sup> can be written as

$$D^{ij} = {}^{ij}D r^2 \qquad {}^{ij} + R^{ijm} r_m + M^{ij}: \qquad (8)$$

The rst term represents the usual di usion of the spin and charge densities, while the second one describes the D'akonov-Perel' [21] spin relaxation

$$i^{j} = 4 \overline{h_{k}^{2} [i^{j} n_{k}^{i} n_{k}^{j}]};$$
 (9)

where  $i; j \in 0$ , the overline denotes the average over the Ferm i surface and  $n_k = h_k = h_k$ . The third term gives rise to precession of the inhom ogeneous spin polarization in the eld of SOI [19]

$$R^{ijm} = 4 \qquad \underset{1}{\overset{\text{wijl}}{\underset{1}{\text{mijl}}} \overline{h_k^1 v_F^m}} : \qquad (10)$$

The nondiagonal elements of the form  $D^{i0}$  appear due to spin-orbit mixing of spin and charge degrees of freedom. They are collected in M<sup>ij</sup>. For Rashba SOIM<sup>i0</sup> have been calculated in [7, 8]. In general case

$$M^{i0} = \frac{\overline{h_k^3} \varrho n_k^i}{\varrho \varrho k} r : \qquad (11)$$

W hen a time independent homogeneous electric eld is applied to the system one has  $_0 = eE x$  and  $D_0^0 =$ 

 $2N_0eE x$ . At the same time, i = 0 and, hence,  $D_i^0 = 0$  at  $i = x_iy_iz$ . Due to charge neutrality the induced charge density  $eD_0 = 0$ . It should be noted that in the system under consideration the charge neutrality can not be full led precisely. The spin polarization accumulated at the strip boundaries gives rise to charge accumulation via the M<sup>0i</sup> terms in (7)-(8). The screening e ect will, how ever, strongly reduce this additional charge, because the screening length of 2D E G is much less than the typical length scale of spin density variations. We will ignore such a small correction and set  $D_0 = 0$  in (7). In this way one arrives to the closed di usion equation for three

components of the spin density. This equation coincides with the usual equation describing di usive propagation of the spin density [19], for exception of the additional term  $M^{i0}D_{0}^{0} = 2N_{0}eE h_{k}^{3}r_{k}^{x}n_{k}^{i} = ^{2}$  due to the external electric eld. Its origin become es more clear in an in - nite system where the spin density is constant in space and only <sup>ij</sup> and M<sup>ij</sup> are retained in (7)-(8). Hence, the solution of (8) at ! = 0 is S\_{i} S\_{0}^{i}, with

$$S_{i}^{b} = D_{i}^{0} = 2 = \frac{N_{0} eE}{2} X_{j} (1)^{ij} h_{k}^{3} \frac{en_{k}^{j}}{ek_{x}};$$
 (12)

where  $( \ ^1 )^{ij}$  is the matrix inverse to (9). Such a phenomenon of spin orientation by the electric eld was predicted in Ref. [16] and recently observed in [22]. In the special case of Rashba SOIh<sub>k</sub> = (k) (k z) it is easily to get from (12) the result of Ref. [16]  $S_{\gamma}^{b} = N_{0}eE$ .

In addition to the di usion equation one needs the boundary conditions. These conditions are that the three components of the spin ux  $I_x^{y}; I_y^{y}; I_z^{y}$  owing in the y direction turn to 0 at y = d=2. The linear response theory, similar to (2) gives

$$I_{i}^{1}(r;t) = \begin{cases} z \\ d^{2}r^{0}dt^{0} \end{cases} \qquad 1_{ij}(r;r^{0};t \quad t) \\ j \end{cases} (r^{0};t^{0}); (13)$$

where the response function is given by

with the one-particle spin-current operator de ned by  $J^1_i$ = (  ${}^iv_1$ +  $v_1$   ${}^i)/4$  and the particle velocity

$$v_1 = \frac{k_1}{m} + \frac{\theta}{\theta k_1} (h_k)$$
 ): (15)

Taking into account (7-6), we obtain from (13-14)

$$I_{i}^{y}(\mathbf{r}) = D \frac{\partial S_{i}}{\partial y} - \frac{1}{2} R^{ijy} (S_{j} - S_{j}^{b}) + {}_{iz} I_{sH} : (16)$$

The rst two terms represent the di usion spin current and the current associated with the spin precession. The third term is the uniform spin-Hall current polarized along the z axis. It is given by

$$I_{sH} = \frac{1}{2} R^{z j y} S_{j}^{b} + e E \frac{N_{0}}{2} v_{F}^{y} \left( \frac{\theta h_{k}}{\theta k^{x}} - h_{k} \right)_{z} : \quad (17)$$

From (10,12) it is easily to see that for R ashba SO I both term s in (17) canceleach otherm aking  $I_{sH} = 0$ , in accordance with [6,7,8,9,10,11,12]. Therefore, in case of the strip the solution of the di usion equation satisfying the boundary condition is  $S_j = {}_{jy}S_y^b$ . Hence, the spin density is uniform and does not accumulate near boundaries. It should be noted that such accumulation can, how ever,

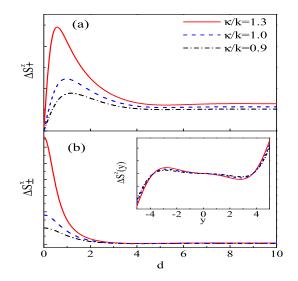


FIG.1: Spin densities  $S_i$  (d=2)  $S^i$  for i = x; z on the boundaries of the strip, as functions of its width d, for =k=0.9,1.0, and 1.3, respectively. The insert shows the dependence of  $S_z$  (y) on the transverse coordinate y. Lengths are measured in units of  $l_{so} = v_F^2 \sim = 2 (v_F y h_{ky})$ 

take place in the ballistic regime of electron scattering [23]. At the same time, as shown in Ref. [11], even in the di usive regime  $I_{sH} \in 0$  for the D resselhaus SO I. This inevitably leads to the spin accumulation. Taking D resselhaus SO I in the form

$$h_k^x = k_x (k_y^2 ^2); h_k^y = k_y (k_x^2 ^2);$$
 (18)

one can see that the bulk spin polarization (12) has a nonzero  $S_x^b$  component,  $R^{zxy} \notin 0$ , while  $R^{zyy} = 0$ . Hence, the solution of the di usion equation (7) with the boundary condition  $I_x^y$  ( d=2) =  $I_z^y$  ( d=2) = 0 is  $S_x; S_z \notin 0$   $S_y = 0$ . Let us de ne  $S_i(y) = S_i(y)$   $S_i^b$ . The dependence of  $S_i$  ( d=2) from the strip width, as well as an example of  $S_z$  coordinate dependence, are shown in Fig. 1. The damped oscillation in the d-dependence of the spin accumulation on the anks of the strip can be seen for the  $S_z$  polarization. Sim ilar oscillations take place also in the coordinate dependence. The length scale of these oscillations is determined by the spin precession in the e ective spin-orbit eld.

The arbitrary units have been used in Fig.q. For a numerical evaluation let us take  $E = 10^4 V/m$ ,  $\frac{h_{k_F}^2}{h_{k_F}^2} = = 0.1$ , and  $=k_F = 0.8$  for a G aA s quantum well of the width w = 100 A doped with 1.5  $1^{10} fm^2$  electrons. We thus obtain j S<sub>z</sub> (d=2)j' 5  $10^{1} m^2$ . The corresponding volume density S<sub>z</sub>=w' 5  $10^{19} m^3$ , which is within the sensitivity range of the Faraday rotation method [4]. It should be noted that in the considered here "dirty" lim it  $\frac{h_{k_F}^2}{h_{k_F}^2} = -1$  the spin-H all current is suppressed by the in purity scattering. A s shown in [11, 12] for D resselhaus and cubic R ashba SO I, this current decreases as

 $\overline{h_{k_F}^2}^2 = -2$  down from its highest universal value. At the same time, an analysis of the di usion equation shows that the accumulated at the anks of the strip spin density decreases slower, as  $\overline{h_{k_F}^2} = -$ . This explains why for the considered above realistic numerical parameters, even in the dirty case, the noticeable spin polarization can be accumulated near the boundary.

U sually, the spin Halle ect is associated with the spin polarization ow, or the spin density accumulation on the sample edges, in response to the electric eld. On the other hand, this e ect can show up in the electric conductance as well. To see such an e ect we take 0-projection of (13), which by de nition is the electric current. The current ow salong the x axis. The corresponding response function  $\sum_{0j}^{x}$  is given by (14) with  $J_0^x = v_x$ . U sing Eqs. (14), (15), (7) and expressing i from (6) one gets the electric current density

$$I^{x} = E + A \frac{\partial S_{z}}{\partial y}; \qquad (19)$$

where is the D rude conductivity and

$$A = e \frac{1}{2^{2}} \quad 2 \overline{v_{F}^{y}} \left( \frac{\theta h_{k}}{\theta k^{x}} \quad h_{k} \right)_{z} + \overline{v_{F}^{x}} \left( \frac{\theta h_{k}}{\theta k^{y}} \quad h_{k} \right)_{z} \quad : (20)$$

The total current is obtained by integrating (19) over y. Therefore, the spin-H all correction to the strip conductance

$$G = \frac{A}{E} (S_z (d=2) \quad S_z (d=2)) = \frac{2A}{E} S_z (d=2) :$$
 (21)

Hence, the dependence of G on the strip width coincides with that of the spin density shown in Fig.1a.

In conclusion, we employed the di usion approximation to study the spin-Halle ect in an in nite 2D strip. In case of the D resselhaus spin-orbit interaction this effect leads to spin accumulation near the anks of the strip, as well as to a correction to the longitudinal electric conductance. Both, the spin accumulation and the conductance exhibit damped oscillations as a function of the strip width.

This work was supported by the Taiwan NationalScience CouncilNSC 93-2112-M -009-036 and RFBR G rant No 030217452.

Sam arth, eds., Sem iconductor Spintronics and Quantum Computation (Springer-Verlag, Berlin, 2002); I. Zutic, J. Fabian, and S. Das Sarm a, Rev. M od. Phys. 76, 323 (2004).

- M.I.D yakonov, V.I.Perel, Phys.Lett.A 35, 459 (1971);
   J.E.H irsch, Phys. Rev. Lett 83, 1834 (1999).
- [3] S.M urakam i, N.N agaosa, and S.-C. Zhang, Science 301, 1348 (2003); J.Sinova et.al., Phys. Rev. Lett. 92, 126603 (2004); D. Culcer et. al., Phys. Rev. Lett. 93, 046602 (2004).
- [4] Y.K.Kato, et. al., Science 306, 1910 (2004)
- [5] J.W underlich et.al, Phys.Rev.Lett.94, 047204 (2005)
- [6] J. I. Inoue, G. E. W. Bauer, and L.W. Molenkamp, Phys. Rev. B 70, 041303 (2004); E. I. Rashba, condmat/0409476 (2004) (unpublished); O. Chalaev and D. Loss, cond-mat/0407342 (unpublished).
- [7] E.G.Mishchenko, A.V. Shytov, and B.I.Halperin, Phys. Rev. Lett. 93, 226602 (2004).
- [8] A.A.Burkov, A.S.Nunez, and A.H.M acD onald, Phys. Rev.B 70, 155308 (2004).
- [9] O.V.D im itrova, cond-m at/0405339 (unpublished)
- [10] R.Raim ondi, P.Schwab, Phys. Rev. B 71, 033311 (2005)
- [11] A.G.Malshukov and K.A.Chao, Phys.Rev.B 71, 121308(R) (2005)
- [12] B.A.Bernevig, S.C.Zhang, cond-m at/0411457; K.Nom ura et al, cond-m at/0506189.
- [13] Yu.A.Bychkov and E.I.Rashba, J.Phys.C 17, 6039 (1984)
- [14] G.D resselhaus, Phys.Rev.100, 580 (1955)
- [15] The cubic Rashba interaction should not be confused with the conventional linear Rashba SO I with the wave-vector dependent coupling constant (k). In the latter case SHE / (k)k=E  $_{\rm F}$  1 [9, 12].
- [16] V.M.Edelstein, Solid State Commun., 73, 233 (1990); J.I.Inoue,G.E.W.Bauer, and L.W.Molenkamp, Phys. Rev.B 67, 033104 (2003)
- [17] A A. Abrikosov, L P. Gorkov, and IE. D zyaloshinskii, M ethods of Q uantum Field Theory in Statistical Physics, (D over, New York, 1975)
- [18] B. L. A Itshuler and A. G. A ronov, in Electron-Electron Interactions in D isordered Systems, edited by A. L. E fros and M. Pollak (North-Holland, Amsterdam, 1985).
- [19] A.G.M alshukov and K.A.Chao, Phys. Rev. B 61, R2413-R2416 (2000).
- [20] A.G.Mal'shukov, K.A.Chao, and M.W illander, Phys. Rev. Lett. 76, 3794 (1996); Physica Scripta T 66, 138 (1996).
- [21] M. I.D 'yakonov and V. I. Perel', Sov. Phys. JETP 33, 1053 (1971) [Zh. Eksp. Teor. Fiz. 60, 1954 (1971)].
- [22] Y.K.Kato, et. al., condm at/0502627.
- [23] B.K. Nikolic, et. al., cond-m at/0412595; Q.W ang, L. Sheng, C.S.Ting, cond-m at/0505576.

G.A.Prinz, Science 282, 1660 (1998); S.A.W olfet.al., Science 294, 1488 (2001); Awschalom, D.Loss, and N.